

# ECEn 340 Equations, Prof. Chiang

Equations

$$I_D = I_s e^{\frac{V_D}{V_T}}$$

$$I_E = I_B + I_C$$

$$I_C = \beta I_B$$

$$I_C = I_s e^{\frac{V_{BE}}{V_T}}$$

$$I_C = I_s e^{\frac{V_{BE}}{V_T}} \left( 1 + \frac{V_{CE}}{V_A} \right)$$

$$g_m = I_C / V_T$$

$$r_o = V_A / I_C$$

$$\beta = g_m r_\pi$$

$$I_D = \frac{1}{2} \mu C_{ox} \frac{W}{L} [2(V_{GS} - V_{th}) V_{DS} - V_{DS}^2]$$

$$I_D = \frac{1}{2} \mu C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2$$

$$I_D = \frac{1}{2} \mu C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2 (1 + \lambda V_{DS})$$

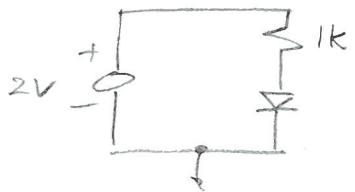
$$g_m = \mu C_{ox} \frac{W}{L} (V_{GS} - V_{th})$$

$$g_m = \sqrt{2 \mu C_{ox} \frac{W}{L} I_D}$$

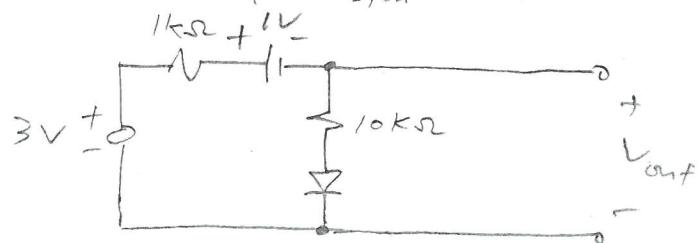
$$g_m = 2 I_D / (V_{GS} - V_{th})$$

$$r_o = 1 / (\lambda I_D)$$

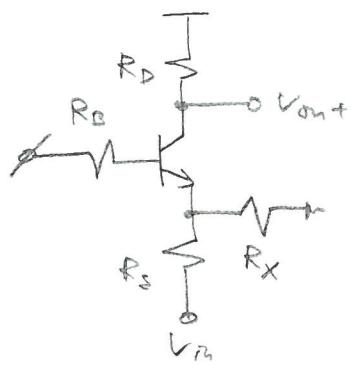
1. Assume the vol. across the diode when it's on is 0.8V. Find  $I_S$



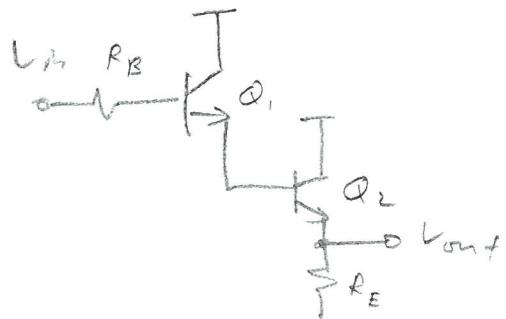
2. Find  $V_{out}$  -  $V_{D(on)} = 0.8V$



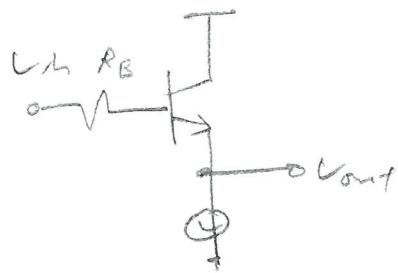
3. Find the gain



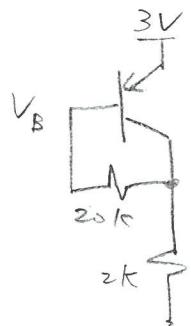
4. Find the gain



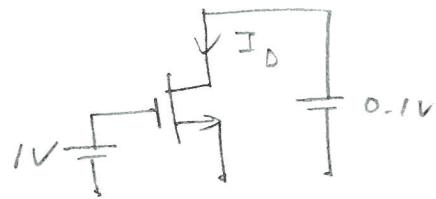
5. Find  $R_{out}$



6. Find  $V_B$ .  $I_C = 1 \text{ mA}$ ,  $\beta = 100$ .

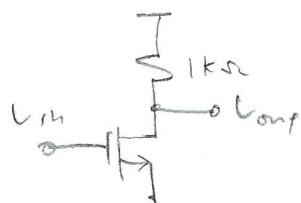


7. Find  $I_D$ .  $V_{th} = 0.4V$ ,  $\mu C_{ox} = 200 \mu A/V^2$ ,  $\frac{W}{L} = 10$ .

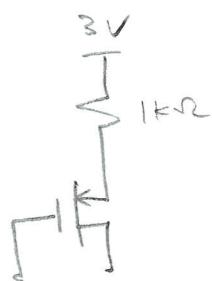


8. A MOSFET has  $I_D = 1mA$ ,  $V_{DS} = 0.5V$ ,  $\lambda = 0.1 V^{-1}$ .  
Find  $I_D$  if  $V_{DS} = 1V$ .

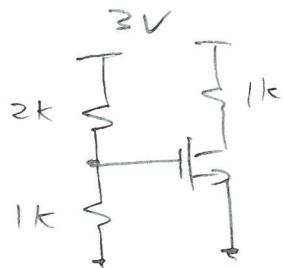
9. Find  $I_D$ .  $\frac{W}{L} = \frac{20}{0.18}$ ,  $\mu C_{ox} = 200 \times 10^{-6}$ ,  $g_m = 0.02$ ,  $\lambda = 0$ .  
Assume transistor is in saturation.



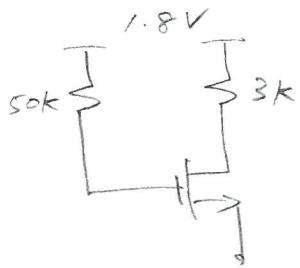
10. Find  $I_D$ .  $V_{SG} - V_{th} = 0.2V$ ,  $V_{th} = 0.4V$



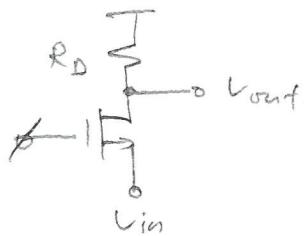
11. Find  $I_D$ .  $V_{th} = 0.4V$ ,  $\mu C_{ox} = 200 \mu A/V^2$ ,  $\frac{W}{L} = 10$ ,  $\lambda = 0$ .



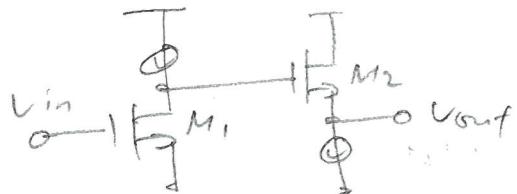
12. Determine max. value of  $\frac{w}{L}$  if  $M_1$  is to remain in sat.  $V_{th} = 0.4 V$ ,  $\mu C_{ox} = 200 \mu A/V^2$ ,  $\lambda = 0$



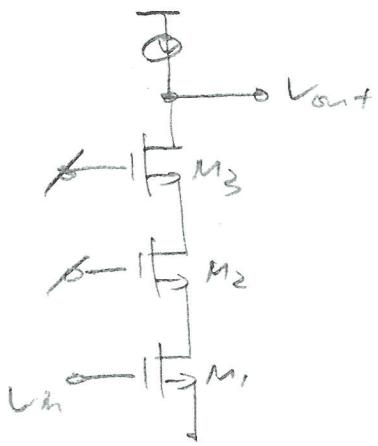
13. Find  $R_D$ .  $G_m = 6$ ,  $R_{in} = 150\Omega$ ,  $\lambda = 0$



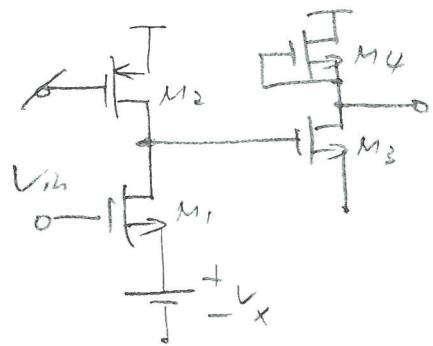
14. Find gain.  $\lambda \neq 0$ .



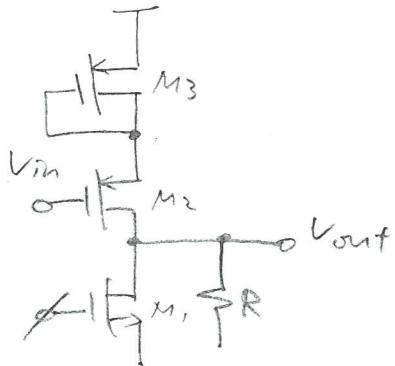
15. Find  $R_{out}$



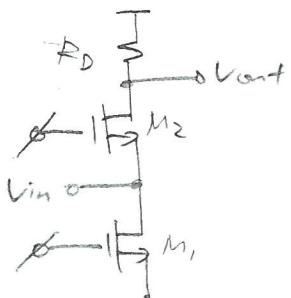
16. Find gain.  $\lambda \neq 0$ .



17. Find gain.  $\lambda_2 = 0$ ,  $\lambda_{1,3} \neq 0$ .

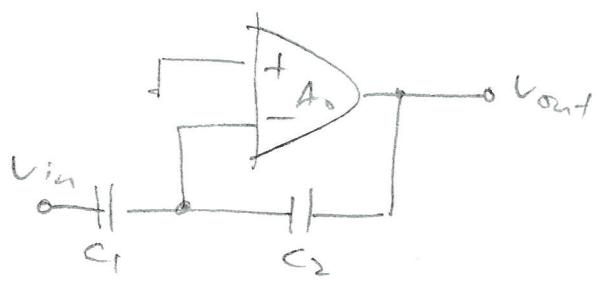


18. Find  $R_m$ .  $\lambda \neq 0$ .

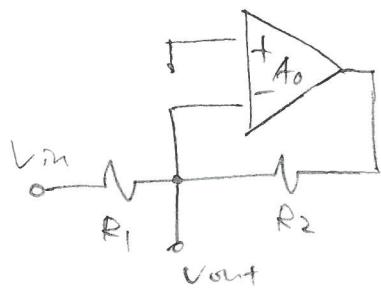


4.

19. Find gain.  $A_o = \infty$



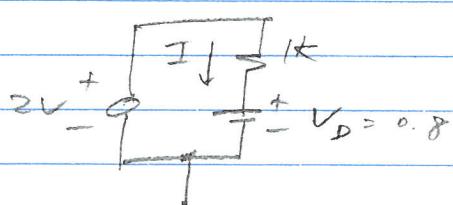
20. Find gain.  $A_o \neq \infty$



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# EEEN 340 Practice Midterm 2 Solutions

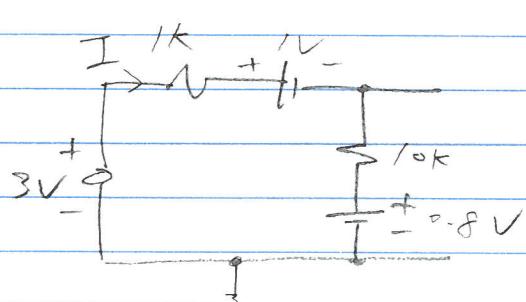
1.



$$I = \frac{2 - 0.8}{1k} = 1.2 \text{ mA}$$

$$I_S = \frac{I_D}{e^{VD/N_T}} = \frac{1.2 \text{ mA}}{e^{0.8/26 \text{ mV}}} = 5.2 \times 10^{-17}$$

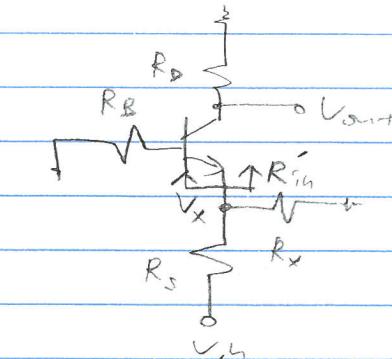
2. Assume diode is on



$$I = \frac{3 - 1 - 0.8}{1k + 10k} = 0.109 \text{ mA}$$

$$V_{out} = 0.8 + I \times 10k = 1.89 \text{ V}$$

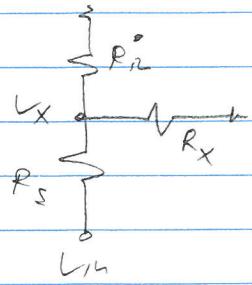
3. S. 5.



$$\frac{V_{out}}{V_{in}} = \frac{V_{out}}{V_x} \frac{V_x}{V_{in}}$$

$$\frac{V_{out}}{V_x} = \frac{g_m R_c}{1 + \frac{R_B}{R_n}}$$

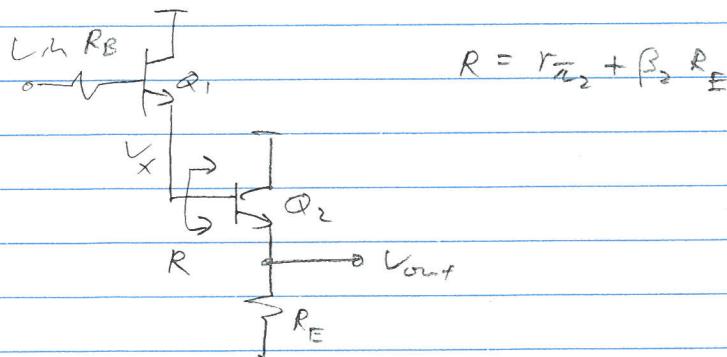
$$R_m = \frac{1}{g_m} + \frac{R_B}{\beta}$$



$$V_x = V_m - \frac{r_n \parallel R_x}{(r_n \parallel R_x) + R_s}$$

$$\frac{V_{out}}{V_m} = \frac{g_m R_c}{1 + \frac{R_B}{r_n}} \frac{\left(\frac{1}{g_m} + \frac{R_E}{\beta}\right) \parallel R_x}{\left[\left(\frac{1}{g_m} + \frac{R_E}{\beta}\right) \parallel R_x\right] + R_s}$$

4.

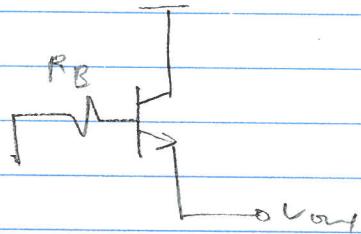


$$\frac{V_x}{V_m} = \frac{g_{m1} (r_{n2} + \beta_2 R_E)}{1 + g_{m1} (r_{n2} + \beta_2 R_E) + \frac{R_B}{r_{n1}}}$$

$$\frac{V_{out}}{V_x} = \frac{g_{m2} R_E}{1 + g_{m2} R_E}$$

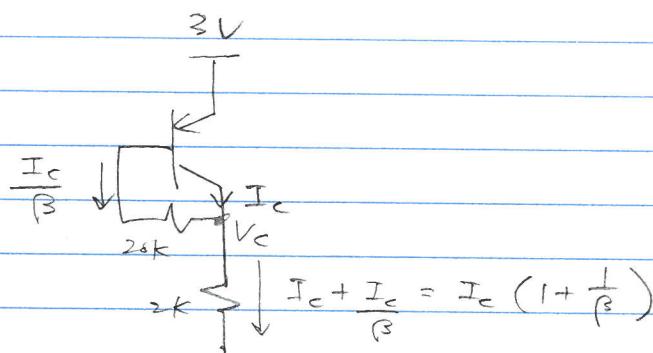
$$\frac{V_{out}}{V_m} = \frac{V_{out}}{V_x} \frac{V_x}{V_m} = \frac{g_{m2} R_E}{1 + g_{m2} R_E} \frac{g_{m1} (r_{n2} + \beta_2 R_E)}{1 + g_{m1} (r_{n2} + \beta_2 R_E) + \frac{R_B}{r_{n1}}}$$

5. S.S.) grounded  $V_{th}$ .



$$A_{out} = \frac{1}{R_L} + \frac{R_L}{\beta}$$

6.



$$V_C = I_C \left(1 + \frac{1}{\beta}\right) 2k = 2.02V$$

$$V_B = V_C + \frac{I_C}{\beta} 20k = 2.02 + \frac{1m}{100} 20k = 2.22V$$

7.

$$V_{DS} < V_{GS} - V_{th} \rightarrow \text{triode}$$

$$I_D = \frac{1}{2} \mu C_{ox} \frac{W}{L} [2(V_{GS} - V_{th}) V_{DS} - V_{DS}^2] \\ = 0.11mA$$

8.

$$I_{D1} = \frac{1}{2} \mu C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2 (1 + \gamma V_{DS1}) \\ I_{D2} = \frac{1}{2} \mu C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2 (1 + \gamma V_{DS2})$$

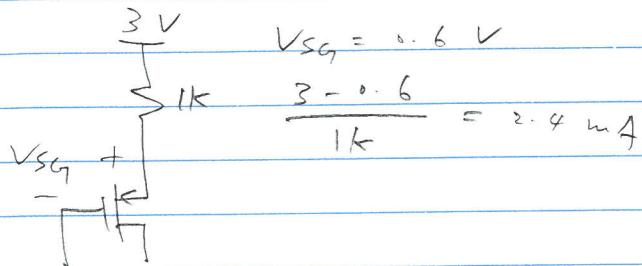
$$I_{D2} = I_{D1} \frac{1 + \gamma V_{DS2}}{1 + \gamma V_{DS1}} = 1.048mA$$

9.

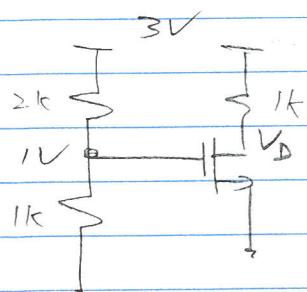
$$g_m = \sqrt{2\mu C_{ox} \frac{W}{L} I_D}$$

$$I_D = \frac{g_m^2}{2\mu C_{ox} \frac{W}{L}} = 9 \text{ mA}$$

10



11



Assume transistor is in sat.

$$I_D = \frac{1}{2} \mu C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2$$

$$= \frac{1}{2} 200 \mu \times 10 (1 - 0.4)^2$$

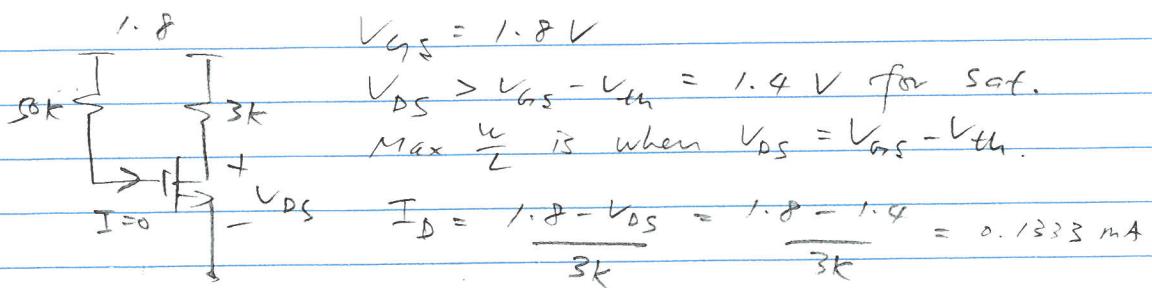
$$= 0.36 \text{ mA}$$

check :

$$V_D = 3 - I_D \times 1k = 2.64 > V_{GS} - V_{th}$$

transistor is in sat.

12



$$I_D = \frac{1}{2} \mu C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2$$

$$\frac{W}{L} = \frac{I_D}{\frac{1}{2} \mu C_{ox} (V_{GS} - V_{th})^2} = \frac{0.1333 \text{ mA}}{\frac{1}{2} 200 \mu \times 1.4^2} = 0.68$$

13

$$G_{m1} = g_m R_D = 6$$

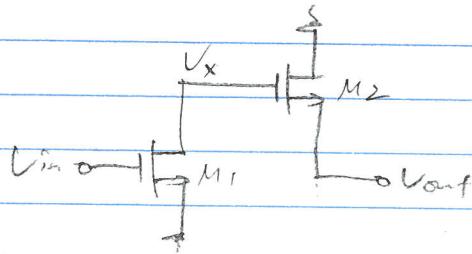
$$R_{in} = \frac{1}{g_m} = 150$$

$$g_m = 150^{-1}$$

$$R_D = \frac{6}{g_m} = 700 \Omega$$

14

S. S.



$$\frac{V_x}{V_{in}} = -g_m, r_o_1$$

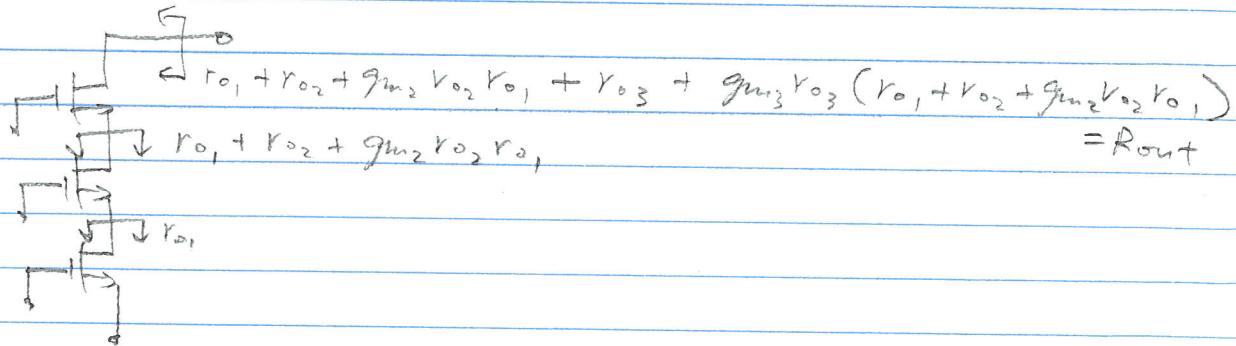
$$R_s = \infty$$

$$\frac{V_{out}}{V_x} = \frac{g_{m2} r_{o2} R_s}{r_{o2} + R_s + g_{m2} r_{o2} R_s} = \frac{g_{m2} r_{o2}}{1 + g_{m2} r_{o2}}$$

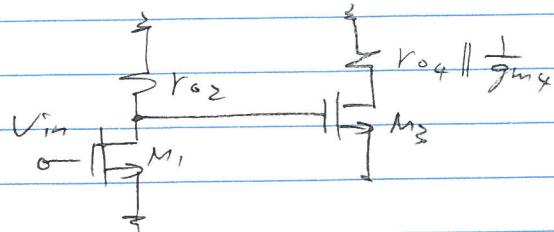
$$\frac{V_{out}}{V_{in}} = \frac{V_{out}}{V_x} \cdot \frac{V_x}{V_{in}} = -g_m, r_o_1 \cdot \frac{g_{m2} r_{o2}}{1 + g_{m2} r_{o2}}$$

15

S. S.

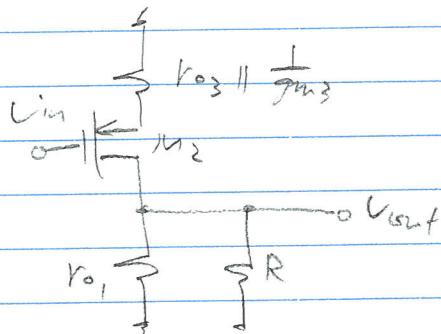


16. S. S.



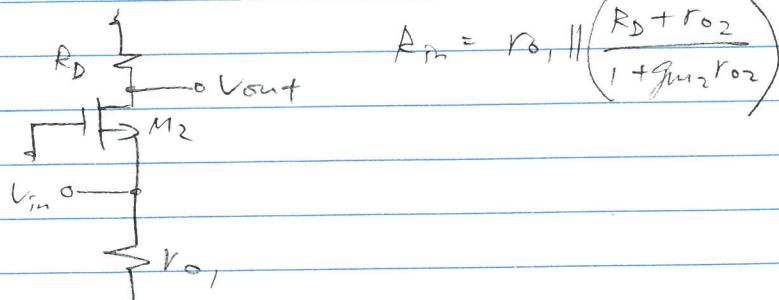
$$\frac{V_{out}}{V_{in}} = g_{m1} (r_0 || r_{o2}) g_{m3} (r_{o3} || r_{o4} || \frac{1}{g_{m4}})$$

17. S. S.



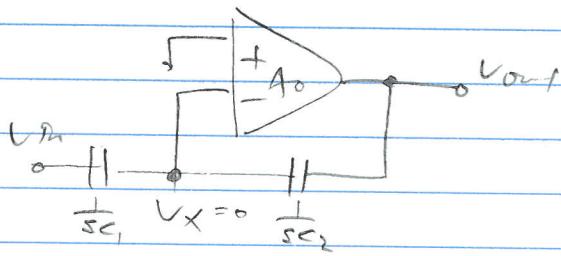
$$\frac{V_{outf}}{V_{in}} = -g_{m2} (r_0 || R) \frac{1}{1 + g_{m2} (r_{o3} || \frac{1}{g_{m3}})}$$

18. S. S.



$$A_m = R_D || \left( \frac{R_D + r_{o2}}{1 + g_{m2} r_{o2}} \right)$$

19

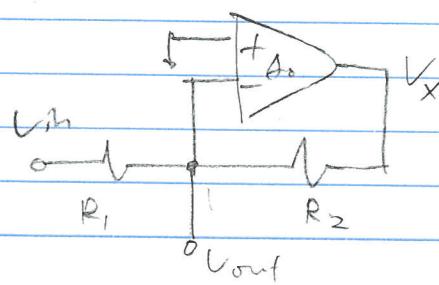


KCL @ amp. negative terminal

$$V_m sC_1 + V_{out} sC_2 = 0$$

$$\frac{V_{out}}{V_m} = \frac{-sC_1}{sC_2} = -\frac{C_1}{C_2}$$

20



$$V_x = A_o (0 - V_{out})$$

$$V_{out} = V_{in} + (V_x - V_{in}) \frac{R_1}{R_1 + R_2}$$

$$V_{out} = V_{in} + (-A_o V_{out} - V_{in}) \frac{R_1}{R_1 + R_2}$$

$$V_{out} \left( 1 + A_o \frac{R_1}{R_1 + R_2} \right) = V_{in} \left( 1 - \frac{R_1}{R_1 + R_2} \right)$$

$$\frac{V_{out}}{V_m} = \frac{1 - \frac{R_1}{R_1 + R_2}}{1 + A_o \frac{R_1}{R_1 + R_2}} = \frac{\frac{R_2}{R_1 + R_2}}{\frac{1 + A_o \frac{R_1}{R_1 + R_2}}{R_1 + R_2}}$$

$$= \frac{\frac{1}{A_o} \frac{R_2}{R_1}}{\frac{1}{A_o} \frac{R_1}{R_1 + R_2} + 1}$$

$$\approx \frac{1}{A_o} \frac{R_2}{R_1} \left( 1 - \frac{1}{A_o \frac{R_1}{R_1 + R_2}} \right)$$